

DC/DC Converter

Application Information

IC Product Name	BD9611MUV
Topology	Buck (Step-Down) Switching Regulator
Type	Non-Isolation

No	Vin[V]	Vo	Operating Frequency[kHz]	Output Capacitor
1	16-48	5V, 10A	150	Aluminum capacitor 220uF Ceramic capacitor 10uF x 4pcs
2	19-32	5V, 10A	250	Ceramic capacitor 47uF x 4pcs
3	16-36	12V, 6A	250	Ceramic capacitor 10uF x 8pcs
4	16-48	12V, 10A	250	Aluminum capacitor 220uF Ceramic capacitor 10uF x 4pcs
5	42	18V, 10A	250	Aluminum capacitor 220uF Ceramic capacitor 10uF x 4pcs
6	24-28	20V, 5A	250	Ceramic capacitor 10uF x 8pcs
7	36-52	24V, 7A	250	Aluminum capacitor 220uF Ceramic capacitor 10uF x 4pcs
8	40	29.4V, 7.5	100	Aluminum capacitor 220uF Ceramic capacitor 10uF x 4pcs

■ Application circuit

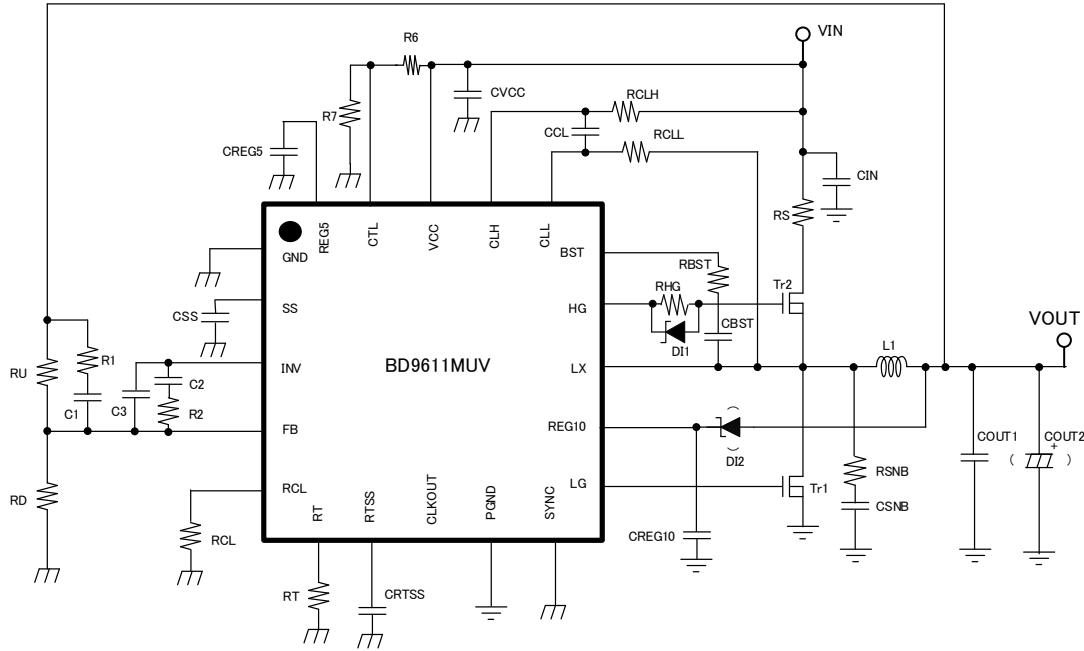


Fig.1 Application circuit

■ RT terminal setting (6-pin)

Terminal State	Operating Frequency setting
External resistor	$F_{osc} = 15900 \times RRT^{-0.955} [kHz]$ RRT: RT resistor [kΩ]

■ SS terminal setting (2-pin)

Terminal State	Soft start setting
External capacitor	$t_{ss} = \frac{CSS \times V_{NON}}{ISS} [s]$ CSS: SS capacitor, VNON: 0.8[V], ISS: 1uA

■ CLL terminal setting (16-pin)、CLH terminal setting (17-pin)

Terminal State	OCP setting
Current sense resistor	$I_{OCP} = \frac{V_{OCPH}}{R_s} [s]$ IOCP: OCP trigger current, VOCPTH: OCP threshold voltage between CLH and CLL configured using RCL Rs: Current sense resistor
RCL resistor	$V_{OCPH} = \frac{0.8}{RRCL} \times 1850 [mV]$ RRCL: RCL resistor

■ CTL terminal setting (19-pin)

Terminal State	IC Operating condition
≥ 2.6V	Normal operating
≤ 2.6V	Power off

■ UVLO detect voltage setting with CTL terminal external resistor

$$R1 = \frac{V_{hys}}{I_{UVHYS}} [\Omega]$$

$$R2 = \frac{V_{EXUTH} \times R1}{V_{uv} - V_{EXUTH}} [\Omega]$$

(I_{UVHYS} :CTL pin source current 20uA(typ) V_{EXUTH} :CTL pin output on threshold 2.6V(typ), V_{uv} :UVLO detect voltage)

■ Output voltage setting

$$V_{OUT} = \frac{RU + RD}{RD} \times 0.8 [V]$$

Input/output voltage conditions are required to satisfy the following equations:

$$V_{OUT} = 1.0V \sim V_{IN} \times 0.8[V]$$

The available output voltage is restricted by the following.

This IC's programmable output voltage is limited to the available area shown on Figure 2. In application, the programmable output voltage is restricted from the unavailable area on the graphs due to input-voltage, frequency, high-side minimum off pulse and load current.

◆ Relation Between Frequency and Input-Output Voltage Ratio

This IC has a limitation in programmed output voltage as shown on the following graphs due to the minimum pulse available for feedback control and programmed OCP detect voltage.

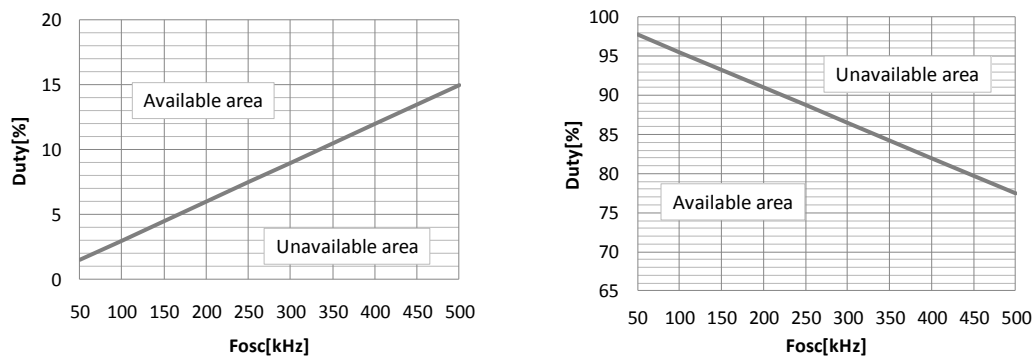


Fig.2 Frequency vs Input-Output Voltage Ratio (Duty)

◆ High-side (HG) Minimum Off Pulse

This IC has a limitation in programmed output voltage due to the Hi-side Minimum Off Pulse for charging BST capacitor (CBST) which adopts the Bootstrap system.

Consider toff=450ns as the OFF duty pulse.

In cases where the configured output voltage is near the input value, the output voltage gets affected by this off pulse. Take into consideration the reduced output voltage limit when the programmed output voltage is near input value.

For example:

(ex.) Programmed output voltage: $V_o = 12V$, Frequency: $f = 250kHz$ ($T = 1/f = 4\mu s$)

OFF_Duty = $1 - (V_o / V_{in})$, Minimum OFF pulse: $toff_min = T \times OFF_Duty$

$toff_min = T \times (1 - V_o / V_{in}) = 4\mu s \times (1 - 12V / V_{in}) \geq 450ns \rightarrow V_{in} \geq 14.95V$

It is necessary that the condition $V_{in} \geq 14.95V$ is satisfied to ensure that the programmed output $V_o = 12V$ is reached.

Additionally, take into consideration the R_{on} voltage drop of the high-side FET, the DCR of coil and the PCB pattern impedance.

◆ Load current

There are no limitations on the load current when the programmed output voltage holds the condition $V_o \geq 10V$. However, certain limitations are imposed when V_o is under 10V because of the Pre-bias sequence.

Please refer to PRE-BIAS as the following..

◆ PRE-BIAS

This IC is designed not to sink large current from V_o , even if V_o had been biased at high voltage upon startup. However, there is a potential of an increase in output voltage through Body-Di of BST, during the charge cycle of switching. This happens when the programmed output voltage is under 10V.

To prevent this, connect a load resistor between V_o and PGND to serve as discharge path when using $V_o < 10V$. Please use the table in Figure 3 as reference in choosing the discharge resistance value.

This issue does not exist when $V_o \geq 10V$.

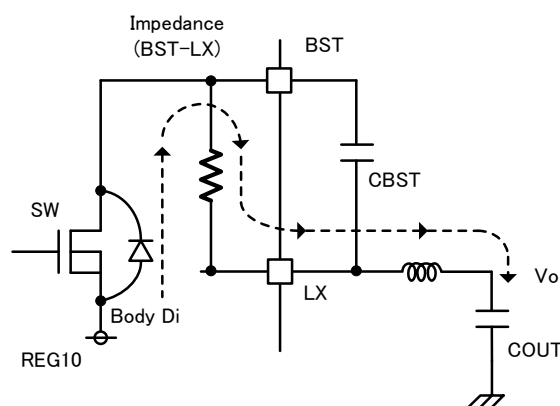


Fig.3 Current Passes Through PRE-BIAS at Low Output Voltage Setting

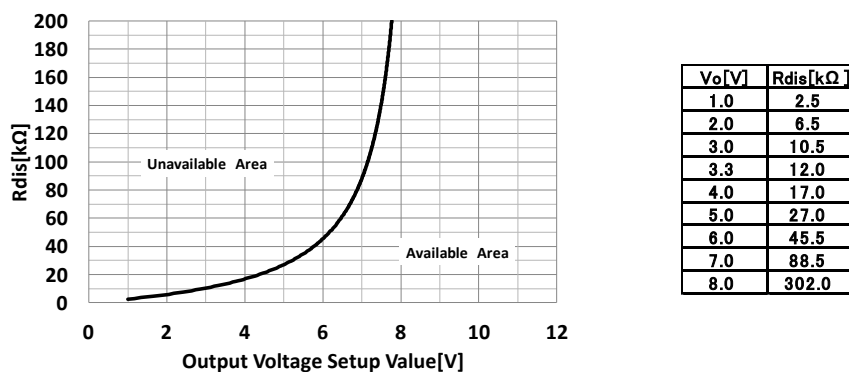


Fig.4 Output Voltage Setting vs Load Resistance

◆ LX terminal snubber circuit

We recommend to connect the snubber circuit R_{SNB} and C_{SNB} to prevent from exceeding the maximum operating voltage 56V. When LX terminal voltage is achieved the maximum operating voltage 56V, it has the possibility to destroy the IC.

■ Evaluation board schematic

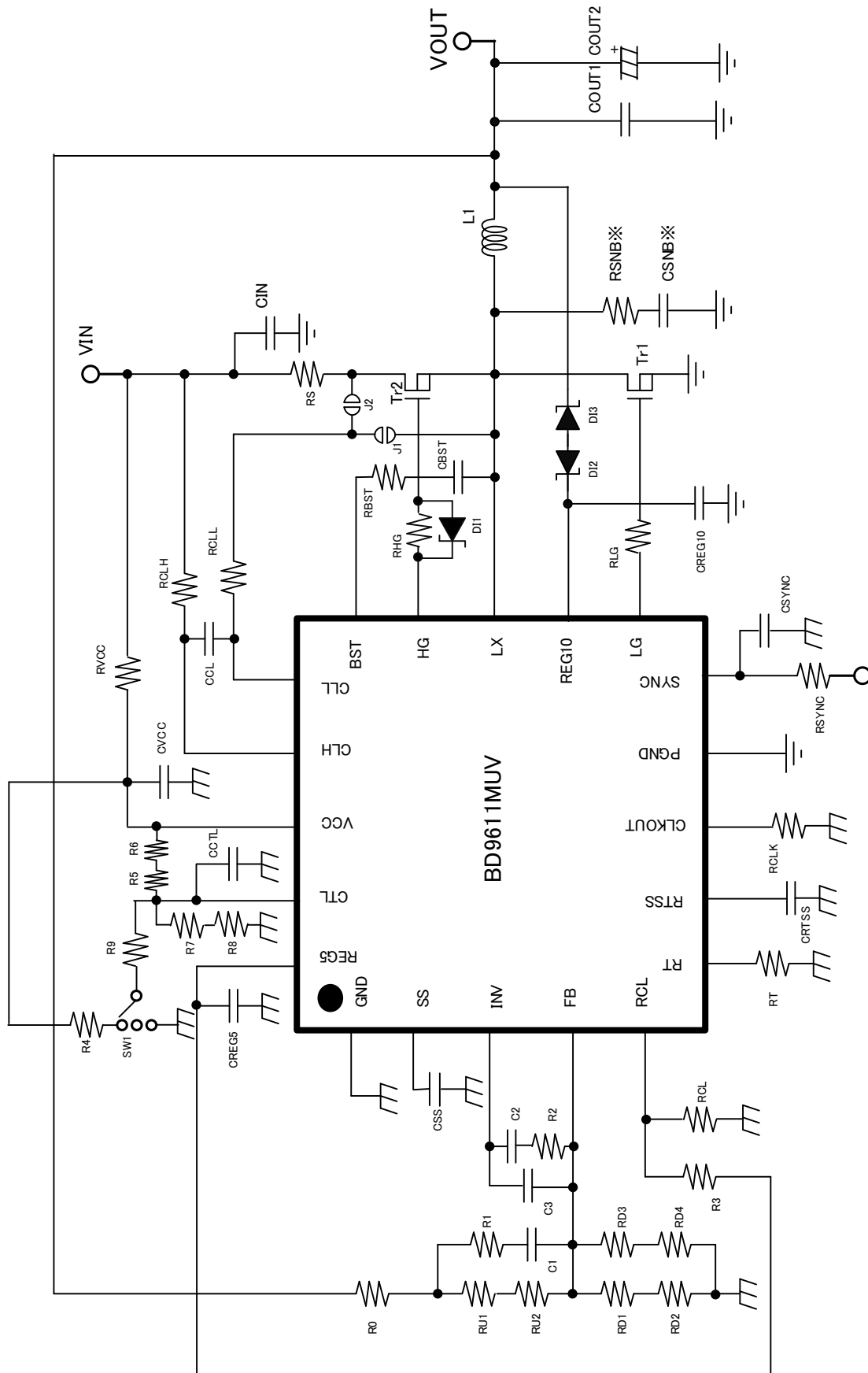


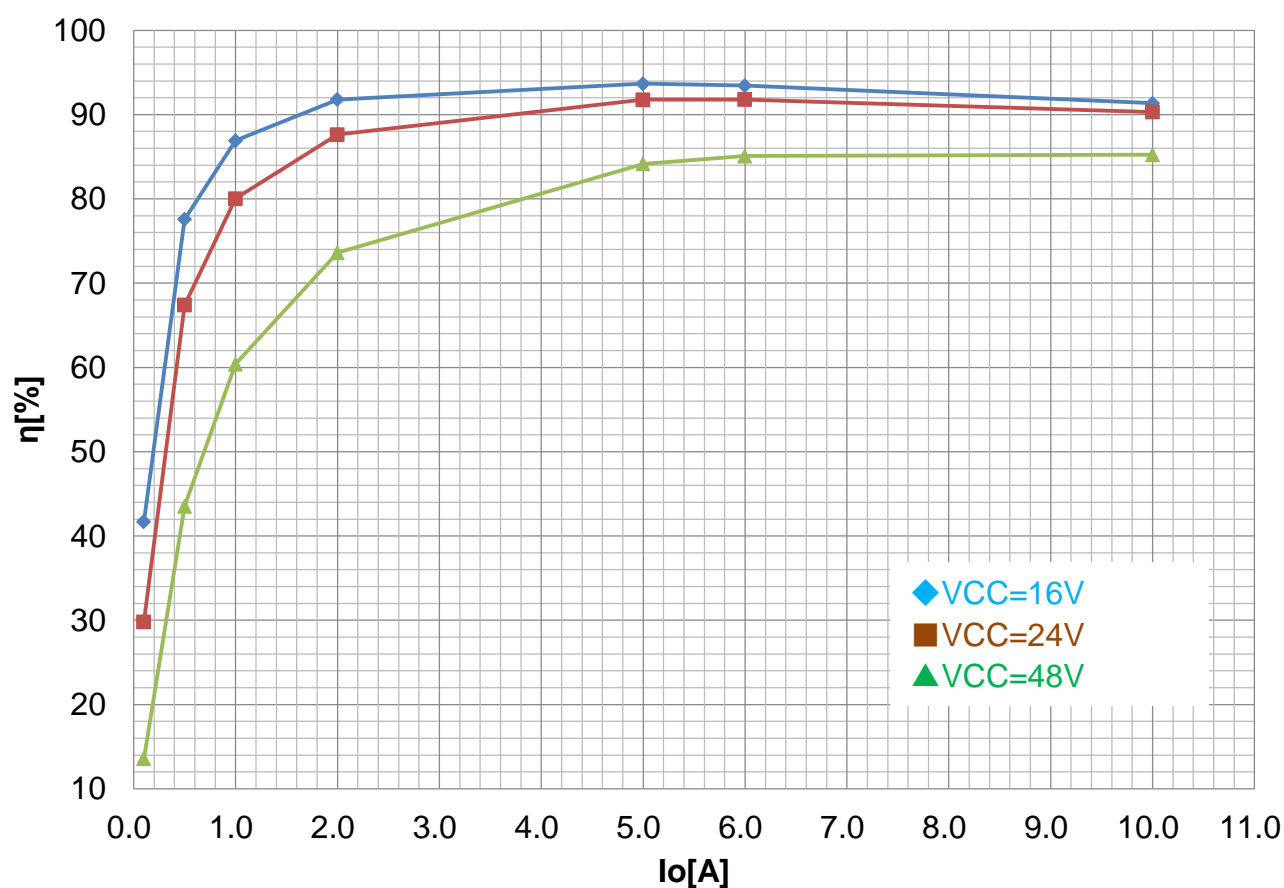
Fig.5 Evaluation board schematic

※There is no layout pattern of RSNB and CSNB. We recommend to connect the RSNB and CSNB to prevent from the ringing voltage of LX terminal.

■ Bill of Materials

1. VO=5V 10A (VIN=16-48V,fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	1000pF	50V, B1, ±10%	GRM188B11H102KA01D	MURATA	1608
1	C2	Ceramic Capacitor	0.047uF	50V, B1, ±10%	GRM188B11H473KA01D	MURATA	1608
1	C3	Ceramic Capacitor	100pF	50V, B1, ±10%	GRM188B11H101KA01D	MURATA	1608
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, ±10%	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
1	COUT2	Ceramic Capacitor	220uF	50V	UVR1H221MPD1TD	nichicon	φ 10
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, ±10%	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.1uF	25V, X5R, ±10%	GRM155R61E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.01uF	16V, X7R, ±10%	GRM188R71C103KA01D	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
1	DI1	Diode	-	20V,1A	RB161VA-20	ROHM	2513
1	L1	Inductor	7.7uH	± 20%,9.85m Ω (max),10A	CDEP147NP-7R7MC-95	SUMIDA	14.9×14.9
1	R1, R2	Resistor	1kΩ	0.1W,50V,1%	MCR03EZPFX1001	ROHM	1608
1	R5	Resistor	27kΩ	0.1W,50V,0.5%	MCR03EZPD2702	ROHM	1608
1	R7	Resistor	5.1kΩ	0.1W,50V,0.5%	MCR03EZPD5101	ROHM	1608
1	R8	Resistor	430Ω	0.1W,50V,0.5%	MCR03EZPD4300	ROHM	1608
1	RCL	Resistor	20kΩ	0.1W,50V,0.5%	MCR03EZPD2002	ROHM	1608
1	RD1	Resistor	3.6kΩ	0.1W,50V,0.5%	MCR03EZPD3601	ROHM	1608
1	RHG	Resistor	10Ω	0.1W,50V,1%	MCR03EZPFX10R0	ROHM	1608
1	RS	Resistor	10mΩ	1W,1%	PMR50HZPFU10L0	ROHM	5025
1	RSNB※	Resistor	22Ω	0.2W,50V,0.5%	ESR03EZPD22R0	ROHM	1608
1	RT	Resistor	75kΩ	0.1W,50V,0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	15kΩ	0.1W,50V,0.5%	MCR03EZPD1502	ROHM	1608
1	RU2	Resistor	3.9kΩ	0.1W,50V,0.5%	MCR03EZPD3901	ROHM	1608
2	Tr1,Tr2	FET	60V/22A	60V,26m Ω max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
11	CSYNC,J2,R0,R6,R8,RBST,RCLH,RCLL,RD2,RLG,RVCC						Short
12	C3,CCL,DI2,DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC						Open

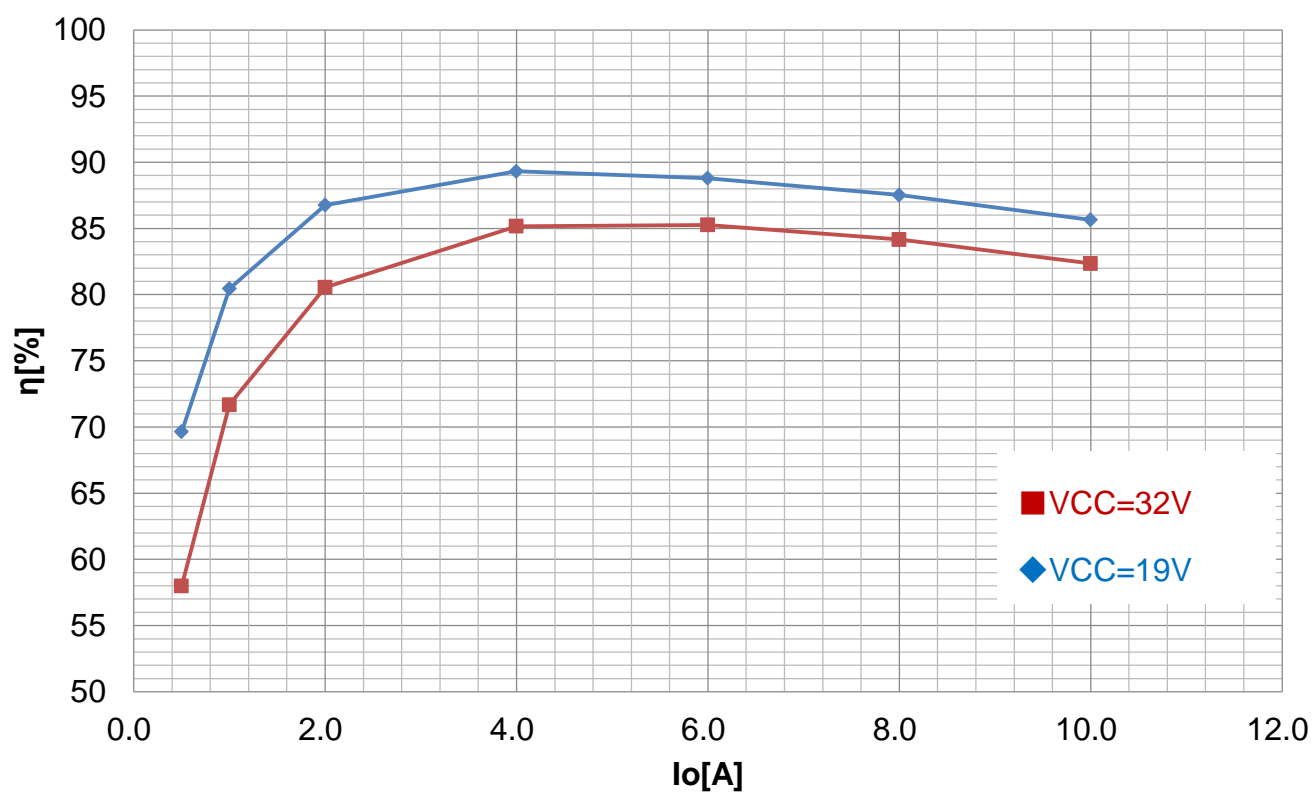


■ Bill of Materials (continued)

2. $V_O=5V$ 10A ($V_{IN}=19-32V, f_{osc}=250kHz$)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	1000pF	50V, B1, $\pm 10\%$	GRM188B11H102KA01D	MURATA	1608
1	C2	Ceramic Capacitor	0.033uF	50V, B1, $\pm 10\%$	GRM188B11H333KA61D	MURATA	1608
1	C3	Ceramic Capacitor	330pF	50V, CH, $\pm 5\%$	GRM1552C1H331JA01	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, $\pm 10\%$	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, $\pm 10\%$	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	47uF	16V, B, $\pm 10\%$	GRM32EB31C476KE15L	MURATA	3225
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, $\pm 10\%$	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.10uF	25V, X5R, $\pm 10\%$	GRM155R61E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.010uF	16V, X7R, $\pm 10\%$	GRM188R71C103KA01D	MURATA	1608
1	CSNB ※	Ceramic Capacitor	680pF	50V, CH, $\pm 5\%$	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, $\pm 10\%$	GRM21BB31H105KA12L	MURATA	2012
1	DI1	Diode	-	20V, 1A	RB161VA-20	ROHM	2513
1	L1	Inductor	4.7uH	$\pm 20\%, 15m\ \Omega$ (max), 10A	SRP1235-4R7M	Bourns	13.9 × 13.5
1	R1, R2	Resistor	1k Ω	0.1W, 50V, 1%	MCR03EZPFX1001	ROHM	1608

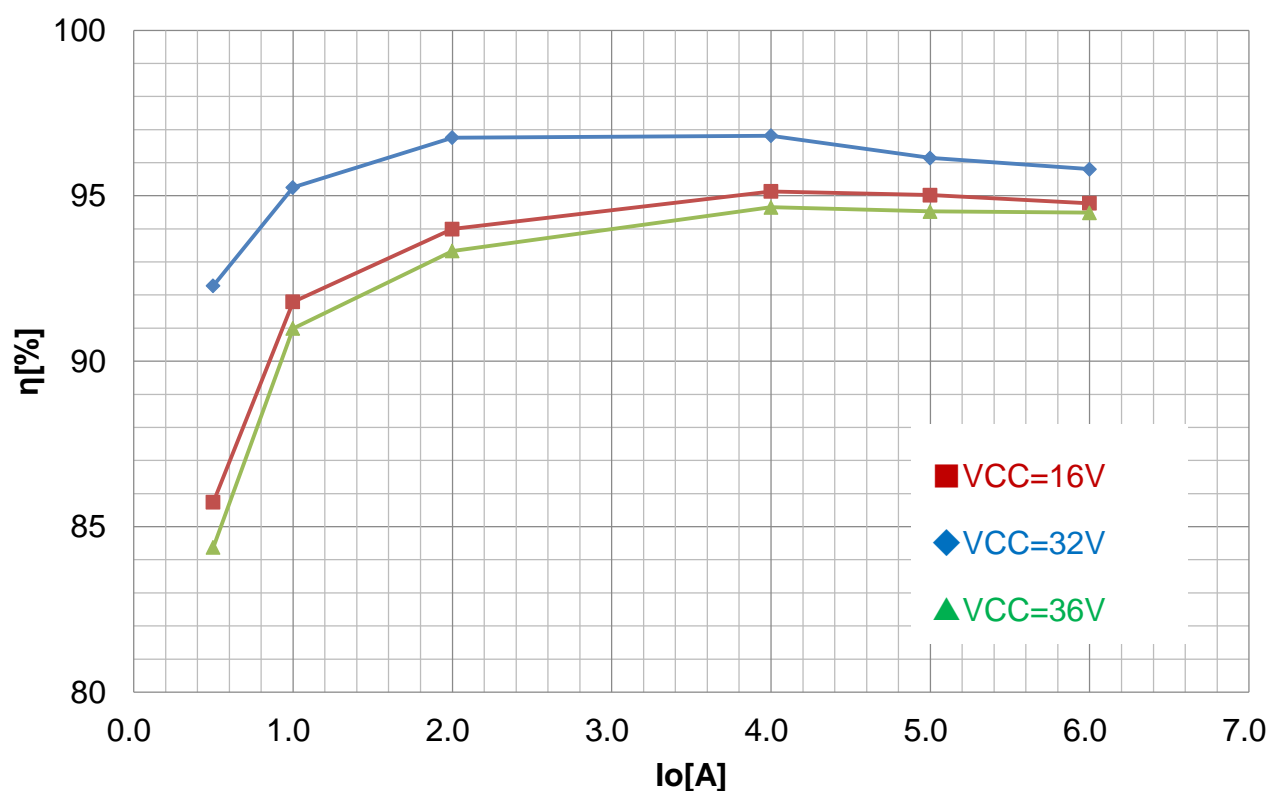
1	R5	Resistor	27k Ω	0.1W,50V,0.5%	MCR03EZPD2702	ROHM	1608
1	R7	Resistor	5.1k Ω	0.1W,50V,0.5%	MCR03EZPD5101	ROHM	1608
1	R8	Resistor	430 Ω	0.1W,50V,0.5%	MCR03EZPD4300	ROHM	1608
1	RCL	Resistor	20k Ω	0.1W,50V,0.5%	MCR03EZPD2002	ROHM	1608
1	RD1	Resistor	3.6k Ω	0.1W,50V,0.5%	MCR03EZPD3601	ROHM	1608
1	RHG	Resistor	10 Ω	0.1W,50V,1%	MCR03EZPFX10R0	ROHM	1608
1	RS	Resistor	10m Ω	2W,1%	PMR100HZPFU10L0	ROHM	6432
1	RSNB ※	Resistor	22 Ω	0.2W,50V,0.5%	ESR03EZPD22R0	ROHM	1608
1	RT	Resistor	75k Ω	0.1W,50V,0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	15k Ω	0.1W,50V,0.5%	MCR03EZPD1502	ROHM	1608
1	RU2	Resistor	3.9k Ω	0.1W,50V,0.5%	MCR03EZPD3901	ROHM	1608
2	Tr1,Tr2	FET	60V/22A	60V,26m Ω max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
11	CSYNC,J2,R0,R6,R8,RBST,RCLH,RCLL,RD2,RLG,RVCC					Short	
13	C3,CCL,DI2,COUT2, DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC					Open	



■ Bill of Materials (continued)

3. VO=12V 6A (VIN=16V/32V/36V, fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	180pF	50V, CH, ±5%	GRM1882C1H181JA01	MURATA	1608
1	C2	Ceramic Capacitor	0.022uF	50V, B1, ±10%	GRM155B11H223KA61	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, B, ±10%	GRM188B31E474KA75	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, X7R, ±10%	GRM32ER71H106KA12L	MURATA	3225
8	COUT1	Ceramic Capacitor	10uF	50V, X7R, ±10%	GRM32ER71H106KA12L	MURATA	3225
1	CREG10	Ceramic Capacitor	1.0uF	16V, B, ±10%	GRM188B31C105KA92	MURATA	1608
1	CREG5	Ceramic Capacitor	0.10uF	25V, B, ±10%	GRM155B31E104KA87D	MURATA	1005
2	CRTSS, CS S	Ceramic Capacitor	0.010uF	16V, B1, ±10%	GRM188B11C103KA01	MURATA	1608
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
2	DI1, DI2	Diode	-	20V, 1A	RB161VA-20	ROHM	2513
1	L1	Inductor	6.8uH	±20%, 22.0mΩ (max), I _{rms} 9A	SRP1235-6R8	Bourns	13.9 × 13.5
1	R1	Resistor	1kΩ	0.1W, 50V, 1%	MCR03EZPFX1001	ROHM	1608
1	R2	Resistor	2.2kΩ	0.1W, 50V, 1%	MCR03EZPFX2201	ROHM	1608
1	R5	Resistor	27kΩ	0.1W, 50V, 0.5%	MCR03EZPD2702	ROHM	1608
1	R7	Resistor	5.1kΩ	0.1W, 50V, 0.5%	MCR03EZPD5101	ROHM	1608
1	R8	Resistor	430Ω	0.1W, 50V, 0.5%	MCR03EZPD4300	ROHM	1608
3	RBST, RHG, R LG	Resistor	10Ω	0.1W, 50V, 1%	MCR03EZPFX10R0	ROHM	1608
1	RCL	Resistor	20kΩ	0.1W, 50V, 0.5%	MCR03EZPD2002	ROHM	1608
1	RD1	Resistor	10kΩ	0.1W, 50V, 0.5%	MCR03EZPD1002	ROHM	1608
1	RS	Resistor	5mΩ	2W, 1%	PMR100HZPFU5L00	ROHM	6432
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	RT	Resistor	39kΩ	0.1W, 50V, 0.5%	MCR03EZPD3902	ROHM	1608
1	RU1	Resistor	120kΩ	0.1W, 50V, 0.5%	MCR03EZPD1203	ROHM	1608
1	RU2	Resistor	20kΩ	0.1W, 50V, 0.5%	MCR03EZPD2002	ROHM	1608
2	Tr1, Tr2	FET	60V/22A	60V, 26mΩ max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
9	CSYNC, DI3, J2, R0, R6, RCLH, RCLL, RD2, RVCC					Short	
13	C3, CCL, COUT2, CSNB, J1, R3, R4, R9, RCLK, RD3, RD4, RSNB, RSYNC					Open	

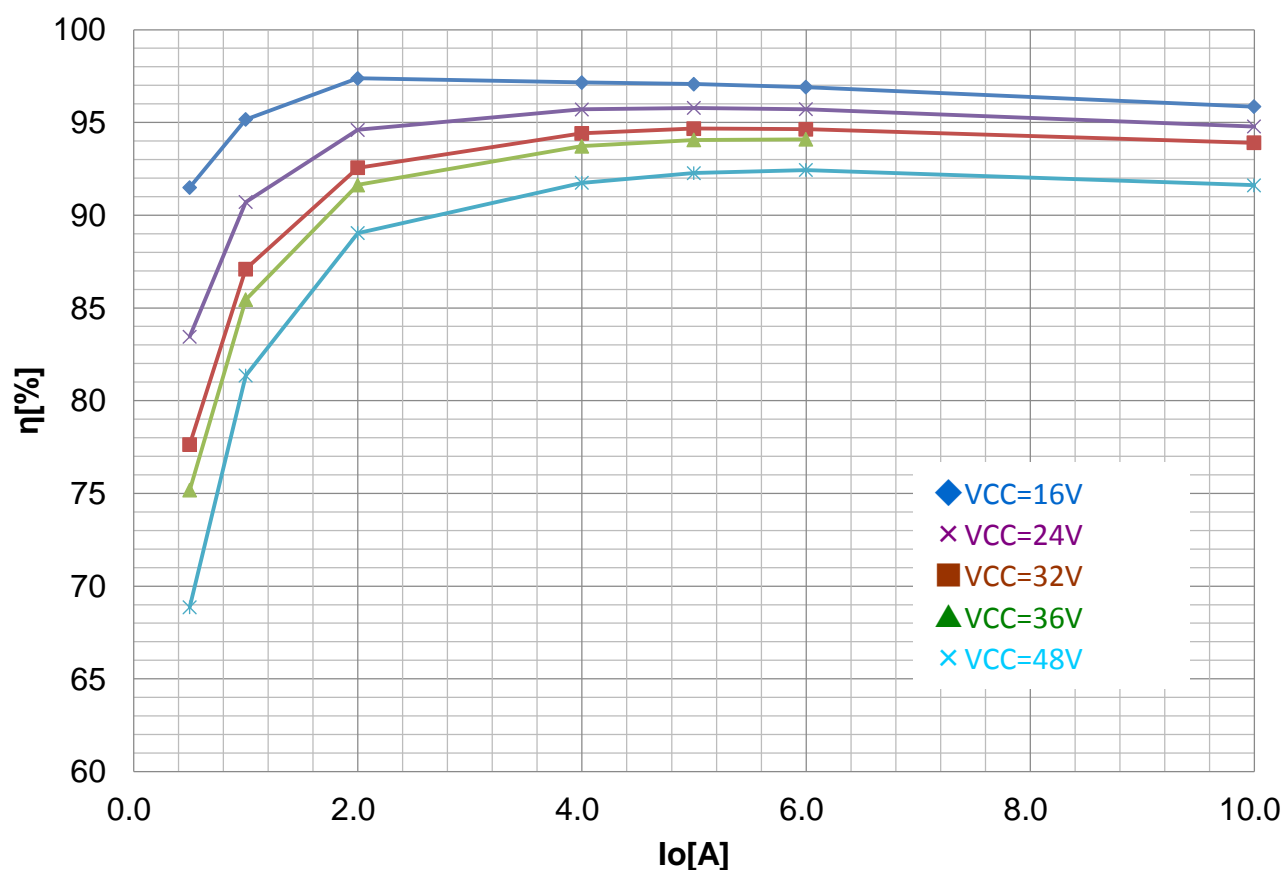


■ Bill of Materials (continued)

4. VO=12V 10A(VIN=16V-48V,fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	100pF	50V, CH, ±5%	GRM1552C1H101JA01	MURATA	1005
1	C2	Ceramic Capacitor	4700pF	50V, B1, ±10%	GRM155B11H472KA01	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, ±10%	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
1	COUT2	Ceramic Capacitor	220uF	50V	UVR1H221MPD1TD	nichicon	φ 10
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, ±10%	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.10uF	25V, X5R, ±10%	GRM155R61E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.010uF	16V, X7R, ±10%	GRM188R71C103KA01D	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
2	DI1, DI2	Diode	-	20V, 1A	RB161VA-20	ROHM	2513
1	L1	Inductor	4.7uH	±20%, 14mΩ(max), 13A	CDEP1411NP-4R7MC-95	SUMIDA	14.9 × 14.9
1	R1	Resistor	1kΩ	0.1W, 50V, 1%	MCR03EZPFX1001	ROHM	1608
1	R2	Resistor	5.1kΩ	0.1W, 50V, 1%	MCR03EZPFX5101	ROHM	1608
1	R5	Resistor	27kΩ	0.1W, 50V, 0.5%	MCR03EZPD2702	ROHM	1608

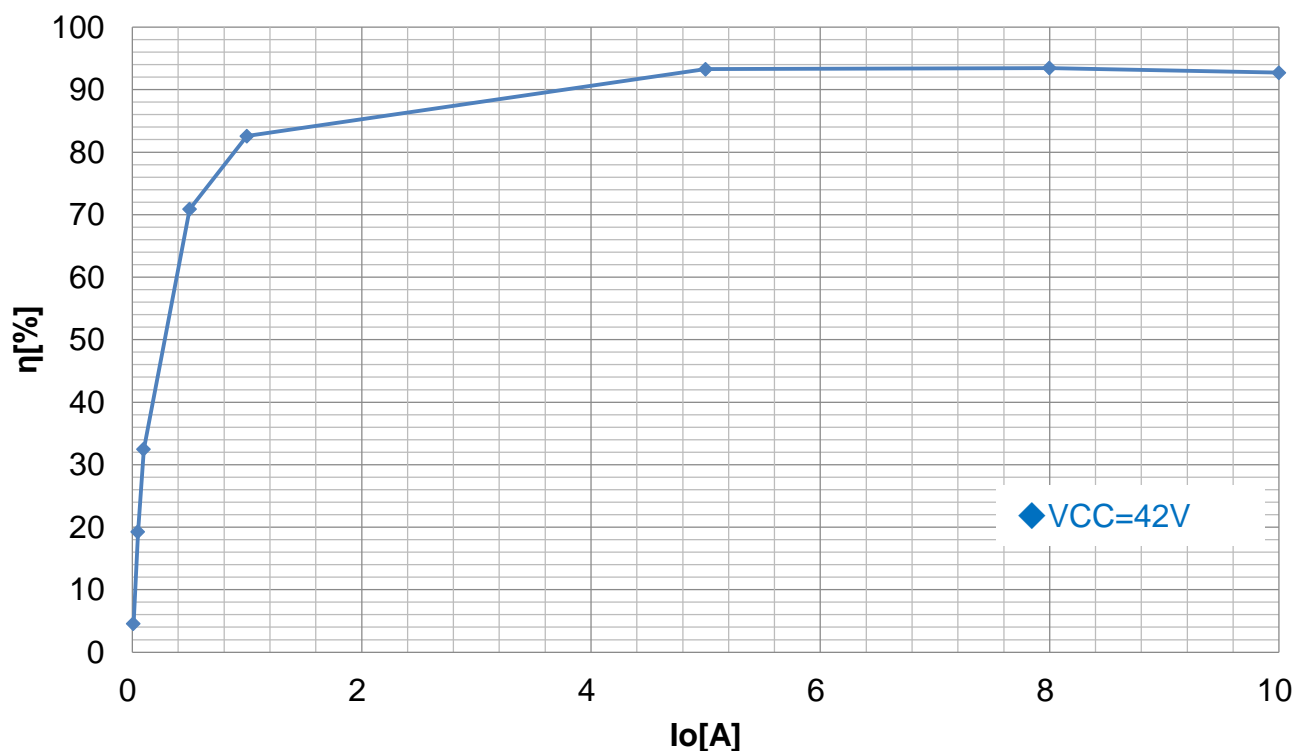
1	R7	Resistor	5.1k Ω	0.1W,50V,0.5%	MCR03EZPD5101	ROHM	1608
1	R8	Resistor	430 Ω	0.1W,50V,0.5%	MCR03EZPD4300	ROHM	1608
1	RCL	Resistor	18k Ω	0.1W,50V,0.5%	MCR03EZPD1802	ROHM	1608
1	RD1	Resistor	10k Ω	0.1W,50V,0.5%	MCR03EZPD1002	ROHM	1608
1	RHG	Resistor	10 Ω	0.1W,50V,1%	MCR03EZPFX10R0	ROHM	1608
1	RS	Resistor	5m Ω	2W,1%	PMR100HZPFU5L00	ROHM	6432
1	RSNB※	Resistor	22 Ω	0.2W,50V,0.5%	ESR03EZPF22R0	ROHM	1608
1	RT	Resistor	75k Ω	0.1W,50V,0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	120k Ω	0.1W,50V,0.5%	MCR03EZPD1203	ROHM	1608
1	RU2	Resistor	20k Ω	0.1W,50V,0.5%	MCR03EZPD2002	ROHM	1608
2	Tr1、Tr2	FET	60V/22A	60V,26m Ω max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
11	CSYNC,J2,R0, R6, R8,RBST,RCLH,RCLL,RD2,RLG,RVCC					Short	
12	C3,CCL,DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC					Open	



■ Bill of Materials (continued)

5. VO=18V 10A(VIN=42V,fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	100pF	50V, CH, ±5%	GRM1552C1H101JA01	MURATA	1005
1	C2	Ceramic Capacitor	4700pF	50V, B1, ±10%	GRM155B11H472KA01	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, ±10%	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
1	COUT2	Ceramic Capacitor	220uF	50V	UVR1H221MPD1TD	nichicon	φ 10
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, ±10%	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.1uF	25V, X5R, ±10%	GRM155R61E104KA87D	MURATA	1005
2	CRTSS、CSS	Ceramic Capacitor	0.01uF	16V, X7R, ±10%	GRM188R71C103KA01D	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
1	DI1	D i o d e	-	20V,1A	RB161VA-20	ROHM	2513
1	L1	Inductor	6.8uH	±20%, 14mΩ(max), 11.5A	IHLP5050FDER6R8M01	VISHAY	13.2 × 12.9
1	R1	Resistor	1kΩ	0.1W,50V,1%	MCR03EZPFX1001	ROHM	1608
1	R2	Resistor	5.1kΩ	0.1W,50V,1%	MCR03EZPFX5101	ROHM	1608
1	R5	Resistor	22kΩ	0.1W,50V,0.5%	MCR03EZPD2202	ROHM	1608
1	R6	Resistor	560Ω	0.1W,50V,0.5%	MCR03EZPD5600	ROHM	1608
1	R7	Resistor	3kΩ	0.1W,50V,0.5%	MCR03EZPD3001	ROHM	1608
1	RCL	Resistor	18kΩ	0.1W,50V,0.5%	MCR03EZPD1802	ROHM	1608
1	RD1	Resistor	10kΩ	0.1W,50V,0.5%	MCR03EZPD1002	ROHM	1608
1	RHG	Resistor	10Ω	0.1W,50V,1%	MCR03EZPFX10R0	ROHM	1608
1	RS	Resistor	5mΩ	2W,1%	PMR100HZPFU5L00	ROHM	6432
1	RSNB※	Resistor	22Ω	0.2W,50V,0.5%	ESR03EZPF22R0	ROHM	1608
1	RT	Resistor	75kΩ	0.1W,50V,0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	200kΩ	0.1W,50V,0.5%	MCR03EZPD2003	ROHM	1608
1	RU2	Resistor	15kΩ	0.1W,50V,0.5%	MCR03EZPD1502	ROHM	1608
2	Tr1、Tr2	FET	60V/22A	60V,26mΩ max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
10	CSYNC,J2,R0,R8,RBST,RCLH,RCLL,RD2,RLG,RVCC					Short	
12	C3,CCL,DI2,DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC					Open	

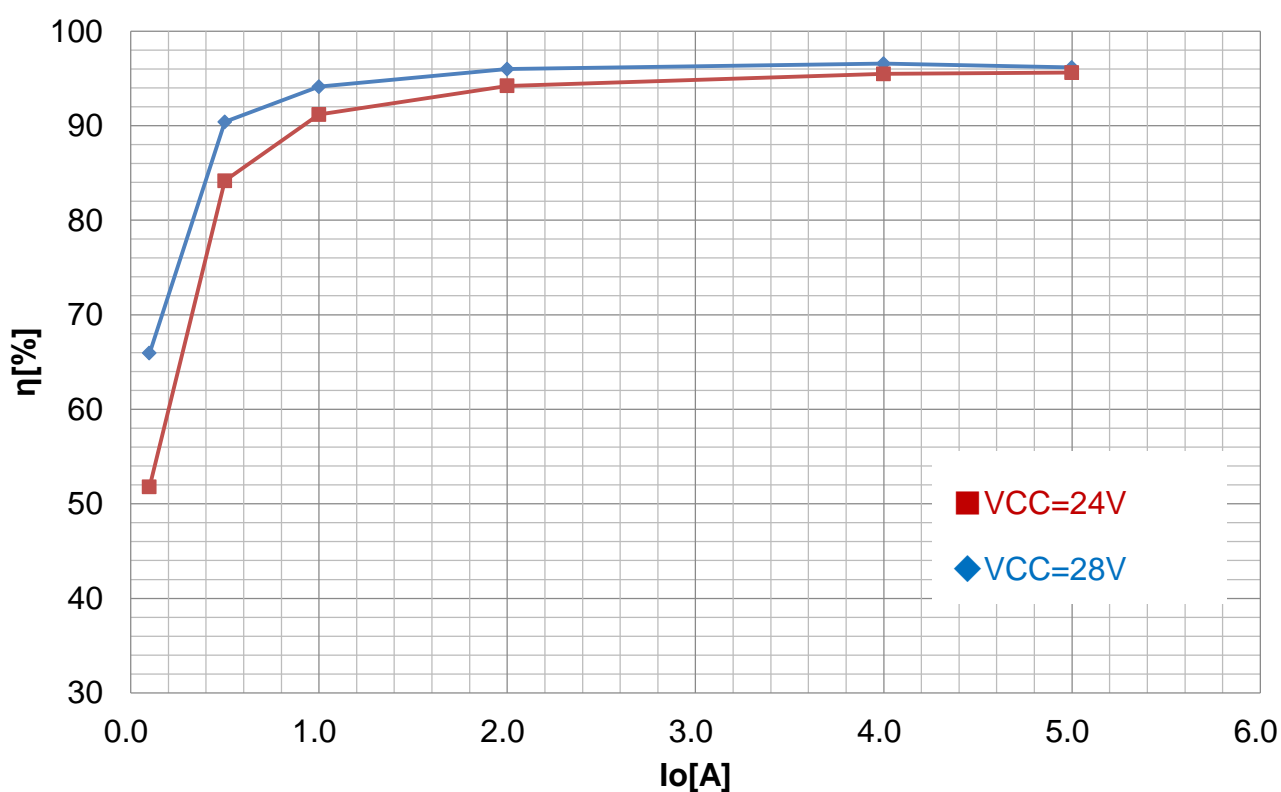


■ Bill of Materials (continued)

6. VO=20V 5A (VIN=24V/28V, fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
2	C1,C3	Ceramic Capacitor	220pF	100V, CH, ±5%	GRM1882C2A221JA01	MURATA	1608
1	C2	Ceramic Capacitor	0.022uF	50V, B1, ±10%	GRM155B11H223KA61	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, B, ±10%	GRM188B31E474KA75	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, X7R, ±10%	GRM32ER71H106KA12L	MURATA	3225
8	COUT1	Ceramic Capacitor	10uF	50V, X7R, ±10%	GRM32ER71H106KA12L	MURATA	3225
1	CREG10	Ceramic Capacitor	1.0uF	16V, B, ±10%	GRM188B31C105KA92	MURATA	1608
1	CREG5	Ceramic Capacitor	0.10uF	25V, B, ±10%	GRM155B31E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.010uF	16V, B1, ±10%	GRM188B11C103KA01	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
1	DI1	Diode	-	20V,1A	RB161VA-20	ROHM	2513
1	L1	Inductor	6.8uH	±20%,22.0mΩ(max),I _{rms} 9A	SRP1235-6R8	Bourns	13.9×13.5
1	R1	Resistor	1kΩ	0.1W,50V,1%	MCR03EZPFX1001	ROHM	1608
1	R2	Resistor	680Ω	0.1W,50V,1%	MCR03EZPFX6800	ROHM	1608

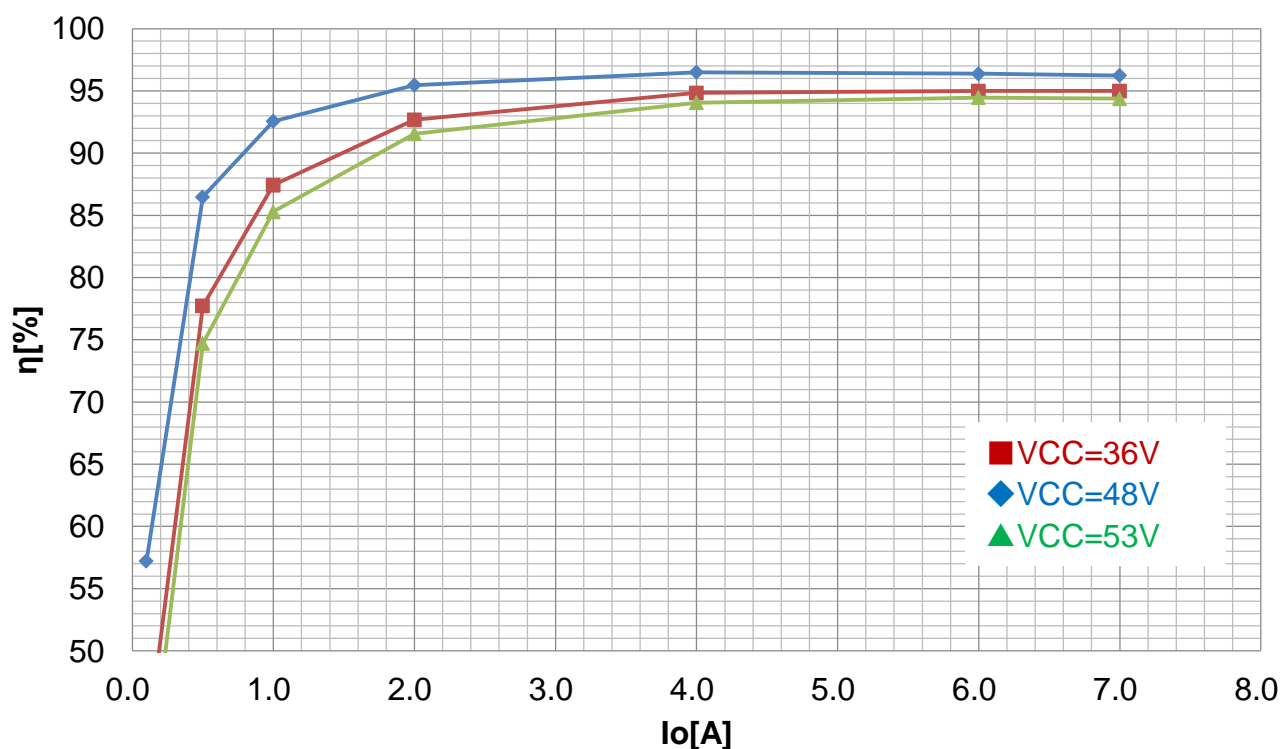
1	R5	Resistor	22k Ω	0.1W,50V,0.5%	MCR03EZPD2202	ROHM	1608
1	R6	Resistor	620 Ω	0.1W,50V,0.5%	MCR03EZPD6200	ROHM	1608
1	R7	Resistor	3k Ω	0.1W,50V,0.5%	MCR03EZPD3001	ROHM	1608
2	RBST,RH G	Resistor	10 Ω	0.1W,50V,1%	MCR03EZPFX10R0	ROHM	1608
1	RCL	Resistor	15k Ω	0.1W,50V,0.5%	MCR03EZPD1502	ROHM	1608
1	RD1	Resistor	7.5k Ω	0.1W,50V,0.5%	MCR03EZPD7501	ROHM	1608
1	RS	Resistor	10m Ω	1W,1%	PMR50HZPFU10L0	ROHM	5025
1	RSNB※	Resistor	22 Ω	0.2W,50V,0.5%	ESR03EZPD22R0	ROHM	1608
1	RT	Resistor	75k Ω	0.1W,50V,0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	180k Ω	0.1W,50V,0.5%	MCR03EZPD1803	ROHM	1608
2	Tr1,Tr2	FET	60V/22A	60V,26m Ω max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
9	CSYNC,J2,R0,R8,RCLH,RCLL,RD2,RLG,RVCC					Short	
12	CCL,DI2,DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC,RU2					Open	



■ Bill of Materials (continued)

7. VO=24V 7A (VIN=36V/48V/53V, fosc=250kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	180pF	50V, C0G, ±5%	GRM1885C1H181JA01D	MURATA	1608
1	C2	Ceramic Capacitor	0.033uF	50V, X7R, ±10%	GRM188R71H333KA01D	MURATA	1608
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, ±10%	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	10uF	50V, B, ±10%	GRM32EB31H106KA12L	MURATA	3225
1	COUT2	Ceramic Capacitor	220uF	50V	UVR1H221MPD1TD	nichicon	φ 10
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, ±10%	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.10uF	25V, X5R, ±10%	GRM155R61E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.010uF	16V, X7R, ±10%	GRM188R71C103KA01D	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, ±5%	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, ±10%	GRM21BB31H105KA12L	MURATA	2012
1	DI1	Diode	-	20V, 1A	RB161VA-20	ROHM	2513
1	R1	Resistor	1.5kΩ	0.1W, 50V, 1%	MCR03EZPFX1501	ROHM	1608
1	R2	Resistor	30kΩ	0.1W, 50V, 1%	MCR03EZPFX3002	ROHM	1608
1	R5	Resistor	43kΩ	0.1W, 50V, 0.5%	MCR03EZPD4302	ROHM	1608
1	R7	Resistor	4.3kΩ	0.1W, 50V, 0.5%	MCR03EZPD4301	ROHM	1608
1	R8	Resistor	330Ω	0.1W, 50V, 0.5%	MCR03EZPD3300	ROHM	1608
1	RCL	Resistor	20kΩ	0.1W, 50V, 0.5%	MCR03EZPD2002	ROHM	1608
1	RD1	Resistor	5.6kΩ	0.1W, 50V, 0.5%	MCR03EZPD5601	ROHM	1608
1	RHG	Resistor	10Ω	0.1W, 50V, 1%	MCR03EZPFX10R0	ROHM	1608
1	RS	Resistor	5mΩ	2W, 1%	PMR100HZPFU5L00	ROHM	6432
1	RSNB※	Resistor	22Ω	0.2W, 50V, 0.5%	ESR03EZPD22R0	ROHM	1608
1	RT	Resistor	75kΩ	0.1W, 50V, 0.5%	MCR03EZPD7502	ROHM	1608
1	RU1	Resistor	160kΩ	0.1W, 50V, 0.5%	MCR03EZPD1603	ROHM	1608
1	RU2	Resistor	2.4kΩ	0.1W, 50V, 0.5%	MCR03EZPD2401	ROHM	1608
2	Tr1, Tr2	FET	60V/22A	60V, 26mΩ max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
1	L1	Inductor	7.7uH	±20%, 9.85mΩ(max), 12.4A	CDEP147NP-7R7MC-95	Sumida	14.9 × 14.9
10	CSYNC, J2, R0, R6, RBST, RCLH, RCLL, RD2, RLG, RVCC					Short	
12	C3, CCL, DI2, DI3, J1, R3, R4, R9, RCLK, RD3, RD4, RSYNC					Open	

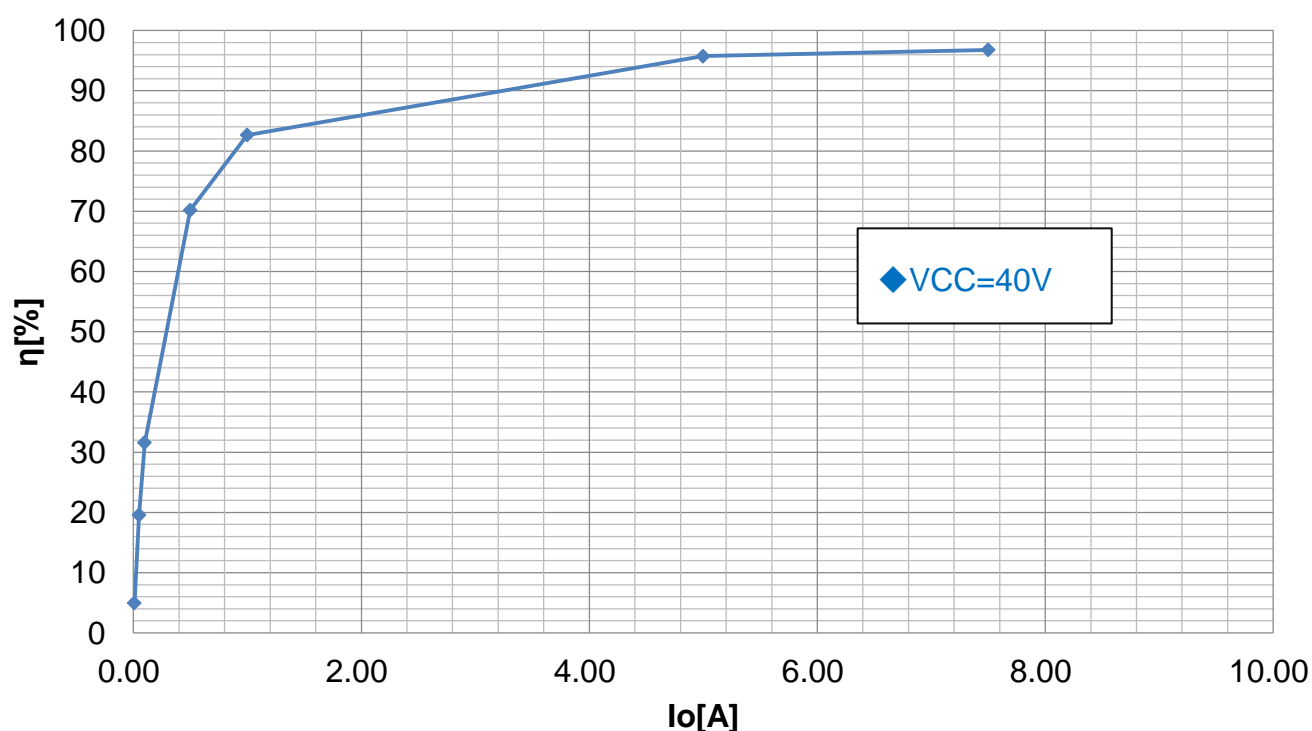


■ Bill of Materials (continued)

8. VO=29.4V 7.5A (VIN=40,fosc=100kHz)

Count	Reference Designator	Type	Value	Description	Manufacturer Part Number	Manufacturer	Configuration (mm)
1	C1	Ceramic Capacitor	100pF	50V, CH, $\pm 5\%$	GRM1552C1H101JA01	MURATA	1005
1	C2	Ceramic Capacitor	4700pF	50V, B1, $\pm 10\%$	GRM155B11H472KA01	MURATA	1005
1	CBST	Ceramic Capacitor	0.47uF	25V, X7R, $\pm 10\%$	GRM188R71E474KA12D	MURATA	1608
4	CIN	Ceramic Capacitor	10uF	50V, B, $\pm 10\%$	GRM32EB31H106KA12L	MURATA	3225
4	COUT1	Ceramic Capacitor	10uF	50V, B, $\pm 10\%$	GRM32EB31H106KA12L	MURATA	3225
1	COUT2	Ceramic Capacitor	220uF	50V	UVR1H221MPD1TD	nichicon	ϕ 10
1	CREG10	Ceramic Capacitor	1.0uF	16V, X7R, $\pm 10\%$	GRM188R71C105KA01D	MURATA	1608
1	CREG5	Ceramic Capacitor	0.1uF	25V, X5R, $\pm 10\%$	GRM155R61E104KA87D	MURATA	1005
2	CRTSS, CSS	Ceramic Capacitor	0.01uF	16V, X7R, $\pm 10\%$	GRM188R71C103KA01D	MURATA	1608
1	CSNB※	Ceramic Capacitor	680pF	50V, CH, $\pm 5\%$	GRM1552C1H681JA01	MURATA	1005
1	CVCC	Ceramic Capacitor	1.0uF	50V, B, $\pm 10\%$	GRM21BB31H105KA12L	MURATA	2012
1	DI1	Diode	-	20V,1A	RB161VA-20	ROHM	2513
1	L1	Inductor	4.7uH	$\pm 20\%$, 4.44m Ω (max), 13A	CDEP1411NP-4R7MC-95MC	SUMIDA	14.9 × 14.9
1	R1	Resistor	1k Ω	0.1W,50V,1%	MCR03EZPFX1001	ROHM	1608
1	R2	Resistor	5.1k Ω	0.1W,50V,1%	MCR03EZPFX5101	ROHM	1608
1	R5	Resistor	22k Ω	0.1W,50V,0.5%	MCR03EZPD2202	ROHM	1608

1	R6	Resistor	560Ω	0.1W,50V,0.5%	MCR03EZPD5600	ROHM	1608
1	R7	Resistor	3kΩ	0.1W,50V,0.5%	MCR03EZPD3001	ROHM	1608
1	RCL	Resistor	16kΩ	0.1W,50V,0.5%	MCR03EZPD1602	ROHM	1608
1	RD1	Resistor	11kΩ	0.1W,50V,0.5%	MCR03EZPD1101	ROHM	1608
1	RHG	Resistor	2.2Ω	0.1W,50V,1%	MCR03EZPFX2R20	ROHM	1608
1	RS	Resistor	5mΩ	2W,1%	PMR100HZPFU5L00	ROHM	6432
1	RSNB※	Resistor	22Ω	0.2W,50V,0.5%	ESR03EZPF22R0	ROHM	1608
1	RT	Resistor	200kΩ	0.1W,50V,0.5%	MCR03EZPD2003	ROHM	1608
1	RU1	Resistor	390kΩ	0.1W,50V,0.5%	MCR03EZPD3903	ROHM	1608
1	RU2	Resistor	3.3kΩ	0.1W,50V,0.5%	MCR03EZPD3301	ROHM	1608
1	Tr1	FET	60V/22A	60V,26mΩ max, 22A, 20W	RSD221N06	ROHM	6595
3	Tr2	FET	60V/22A	60V,26mΩ max, 22A, 20W	RSD221N06	ROHM	6595
1	U1	IC	-	Buck DC/DC Converter, QFN 16pin	BD9611MUV	ROHM	3030
10	CSYNC,J2,R0,R8,RBST,RCLH,RCLL,RD2,RLG,RVCC					Short	
12	C3,CCL,DI2,DI3,J1,R3,R4,R9,RCLK,RD3,RD4,RSYNC					Open	



■ Precautions for use

- (1) This document provides the BOM for evaluation boards. Small parts can also be selected for resistor, capacitor, and coil.
- (2) When miniaturizing a resistor, consider decrease in rated power and withstand voltage.
- (3) When miniaturizing a ceramic capacitor, consider decrease in withstand voltage. In addition, the capacity may be decreased by DC bias characteristics, and the desired characteristics may not be obtained.
- (4) If ceramic capacitor models differ even when they have the same capacity and withstand voltage, the capacity may be decreased by DC bias characteristics depending on the model, and desired characteristics may not be obtained. Be sure to check the DC bias characteristics.
- (5) When miniaturizing a coil, consider increase in direct current resistance and decrease in rated current. An increase in DC resistance can cause a deterioration of power conversion efficiency. A decrease in rated current can saturate the coil when outputting a large current, which may deteriorate efficiency or make it impossible to obtain the desired output current.
- (6) If there is a possibility that the output will short-circuit, use a coil with a rated current that is larger than the maximum IC output current. For example, even when up to 100 mA is actually used for an IC that can output 1 A, select a coil whose rated current is larger than 1 A. If a coil with a small rated current is used, it will be saturated by a large current in the event of output short-circuiting, resulting in a steep increase in output voltage. The IC may be broken down because the processing speed of the overcurrent protecting function of the IC cannot keep up with the increase in voltage.
- (7) This circuit constant is the value for our evaluation board. It may be necessary to adjust the constant for the actual board. Carry out suitable evaluations.